

R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included. When implemented in P-Spice, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in Application Note AN609, "Thermal Simulation of Power MOSFETs on the P-Spice Platform."

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RT1	2.6589	78.8700 m	N/A
RT2	6.5775	1.1503	N/A
RT3	9.6454	108.1800 m	N/A
RT4	46.1182	462.6500 m	N/A
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	19.3342 m	5.5342 u	N/A
CT2	108.8288 m	13.3983 m	N/A
CT3	487.0439 m	139.3863 m	N/A
CT4	1.5446	9.6801 m	N/A

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RF1	6.4734	90.7507 m	N/A
RF2	11.5611	1.2304	N/A
RF3	15.2442	102.0668 m	N/A
RF4	31.7213	376.7825 m	N/A
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	25.1473 m	467.3749 u	N/A
CF2	119.0129 m	5.0200 m	N/A
CF3	902.3964 m	19.2422 m	N/A
CF4	708.6585 m	6.3060 m	N/A

Note

NA indicates not applicable

